

NBL00419

4-8 GHz Low Noise Amplifier

Features:

- Thin Film Hybrid MIC Process
- Field Replaceable RF Connectos
- Reverse Polarity Protection
- Wide Range of DC Supply Voltage

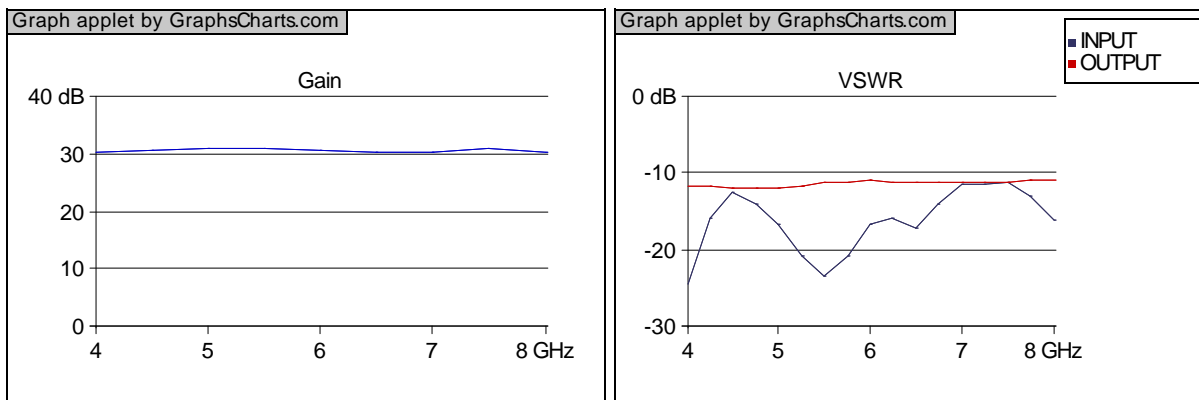
Electrical Performance

Parameter	Min.	Typ.	Max.	Unit	Note
Frequency	4		8	GHz	
Gain	29	30		dB	
Gain Flatness		0.5	1.0	dB(+/-)	
VSWR Input			2.0		
VSWR Output			2.0		
Power @ 1dB Gain Compression Point	15	16		dBm	
Noise Figure		1.7	2.2	dB	
DC Supply Voltage	10	15	17	V	
Supplied Current		90	110	mA	

* RF Input Power: -15 dBm. DC Supply Voltage: +15 V.

** Measured at 25 degC.

Typical Test Data



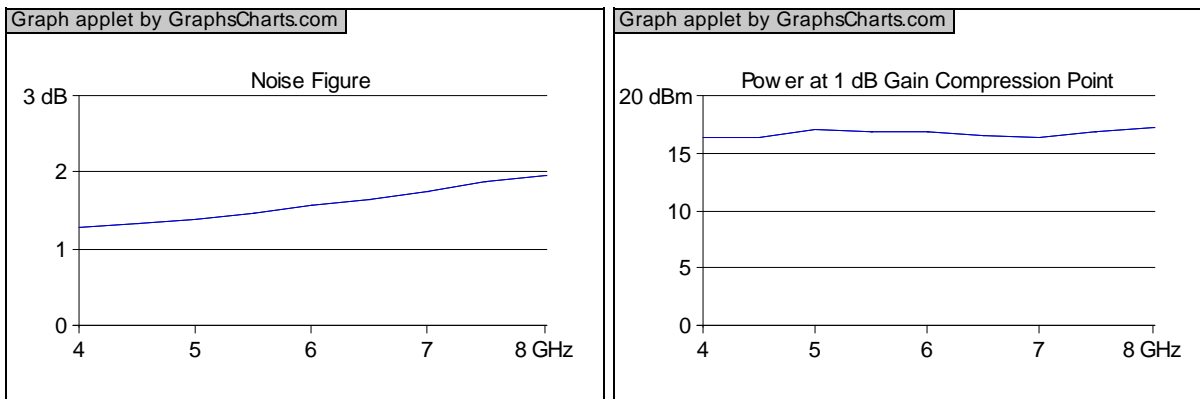
Updated: 9/6/2012



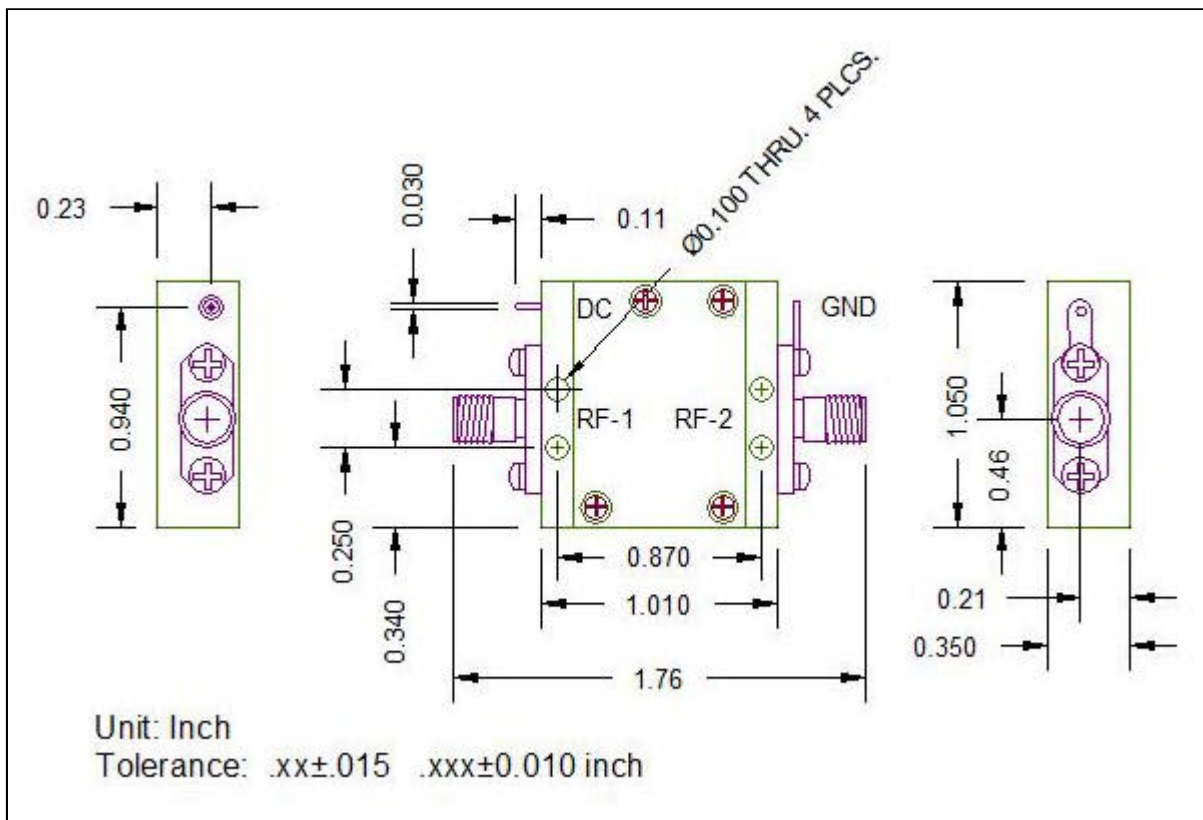
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Outline Drawing



Connector	Type	Pin #	Pin Name	In/Out	Description
RF-1	SMA-F	1	IN	I	RF Input
RF-2	SMA-F	1	OUT	O	RF Output
DC	EMI Filter	1	+12 V	I	DC Power Supply (10-17V)

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GND GROUND LUG 1 GND O Ground

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